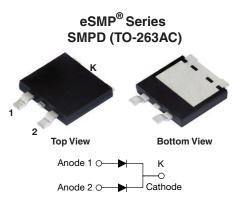
Vishay Semiconductors

# Hyperfast Rectifier, 2 x 15 A FRED Pt<sup>®</sup>



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## LINKS TO ADDITIONAL RESOURCES



PRIMARY CHARACTERISTICS				
I <sub>F(AV)</sub>	2 x 15 A			
V <sub>R</sub>	600 V			
V <sub>F</sub> at I <sub>F</sub> (T <sub>J</sub> = 150 °C)	1.22 V			
t <sub>rr</sub>	30 ns			
T <sub>J</sub> max.	175 °C			
Package	SMPD (TO-263AC)			
Circuit configuration	Common cathode			

## FEATURES

- Hyperfast recovery time, reduced Q<sub>rr</sub>, and soft recovery
- 175 °C maximum operating junction temperature
- For PFC CRM, snubber operation
- Low forward voltage drop
- Low leakage current
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260  $^\circ\mathrm{C}$
- Meets JESD 201 class 2 whisker test
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

### **DESCRIPTION / APPLICATIONS**

State of the art hyperfast recovery rectifiers designed with optimized performance of forward voltage drop and ultrafast recovery time, and soft recovery.

The planar structure and the platinum doped life time control guarantee the best overall performance, ruggedness, and reliability characteristics.

These devices are intended for use in PFC, boost, lighting, in the AC/DC section of SMPS, freewheeling and clamp diodes.

Their extremely optimized stored charge and low recovery current minimize the switching losses and reduce power dissipation in the switching element and snubbers.

### **MECHANICAL DATA**

#### Case: SMPD (TO-263AC)

Molding compound meets UL 94 V-0 flammability rating Halogen-free, RoHS-compliant

Terminals: matte tin plated leads, solderable per J-STD-002

ABSOLUTE MAXIMUM RATINGS							
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS		
Peak repetitive reverse voltage		V <sub>RRM</sub>		600	V		
Average restified forward average	per device	I (1)	T <sub>C</sub> = 130 °C	30	А		
Average rectified forward current	per diode	I <sub>F(AV)</sub> <sup>(1)</sup>	$1_{\rm C} = 130$ C	15			
Non-repetitive peak surge current, per diode		I <sub>FSM</sub>	$T_J = 25 \text{ °C}, 10 \text{ ms}$ sine pulse	160			

<b>ELECTRICAL SPECIFICATIONS</b> (T <sub>J</sub> = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS	
Breakdown voltage, blocking voltage	$V_{BR}, V_{R}$	I <sub>R</sub> = 100 μA	600	-	-		
Forward voltage, per diode	VF	I <sub>F</sub> = 15 A	-	1.63	2.15	V	
	۷F	I <sub>F</sub> = 15 A, T <sub>J</sub> = 150 °C	-	1.22	1.65		
Reverse leakage current, per diode	1_	$V_{R} = V_{R}$ rated	-	-	20	μA	
neverse leakage current, per diode	IR	$T_J = 150 \text{ °C}, V_R = V_R \text{ rated}$	-	-	500	μΑ	
Junction capacitance, per diode	CT	V <sub>R</sub> = 600 V	-	16	-	pF	

Note

<sup>(1)</sup> Mounted on infinite heatsink

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COMPLIANT



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<b>DYNAMIC RECOVERY CHARACTERISTICS</b> ( $T_J = 25 \text{ °C}$ unless otherwise specified)								
PARAMETER	SYMBOL	TEST CO	TEST CONDITIONS			MAX.	UNITS	
		$I_F = 1 \text{ A}, \text{ d}I_F/\text{d}t = 50 \text{ A}$	õs, V <sub>R</sub> = 30 V	-	30	-		
Payaraa raaayary tima par diada	+	$I_F = 0.5 \text{ A}, I_R = 1 \text{ A}, I_{rr}$	= 0.25 A	-	-	30	ns	
Reverse recovery time per diode	t <sub>rr</sub>	T <sub>J</sub> = 25 °C		-	41	-		
		T <sub>J</sub> = 125 °C		-	92	-		
Peak recovery current per diode	1	T <sub>J</sub> = 25 °C	$I_{\rm F} = 15  \text{A},$	-	7	-	А	
Feak recovery current per diode	I <sub>RRM</sub>	T <sub>J</sub> = 125 °C	dI <sub>F</sub> /dt = 500 A/µs, V <sub>B</sub> = 400 V	-	13	-	A	
Poverse recevent charge per diade	0	T <sub>J</sub> = 25 °C		-	150	-	nC	
Reverse recovery charge per diode	Q <sub>rr</sub>	T <sub>J</sub> = 125 °C		-	590	-	ne	

THERMAL - MECHANICAL SPECIFICATIONS							
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS	
Maximum junction and storage temperature range	T <sub>J</sub> , T <sub>Stg</sub>		-55	-	+175	°C	
Thermal resistance, junction to mount, per diode	R <sub>thJM</sub>		-	1.2	1.7	°C/W	
Approximate weight				0.55		g	
Approximate weight				0.02		oz.	
Marking device		Case style SMPD (TO-263AC)		30CI	DH06		



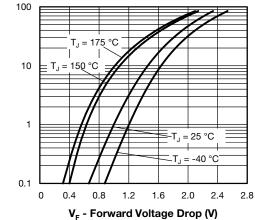


Fig. 1 - Typical Forward Voltage Drop Characteristics, Per Diode

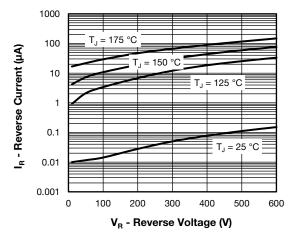


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage, Per Diode

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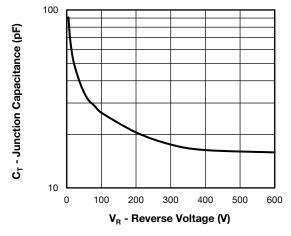


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage, Per Diode

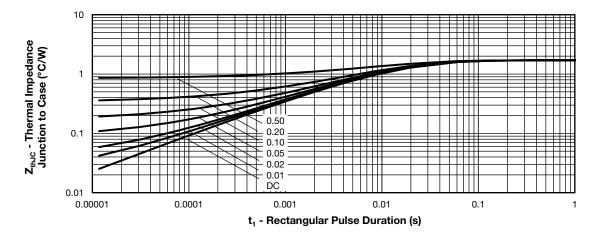
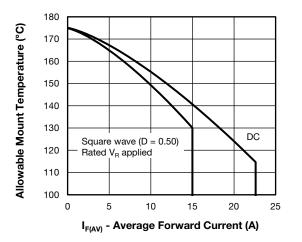
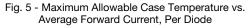


Fig. 4 - Maximum Thermal Impedance Z<sub>thJC</sub> Characteristics, Per Diode



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### Note

<sup>(1)</sup> Formula used:  $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$ ;

 $\begin{array}{l} \mathsf{Pd} = \mathsf{forward} \ \mathsf{power} \ \mathsf{loss} = \mathsf{I}_{\mathsf{F}(\mathsf{AV})} \times \mathsf{V}_{\mathsf{FM}} \ \mathsf{at} \ (\mathsf{I}_{\mathsf{F}(\mathsf{AV})}/\mathsf{D}) \ (\mathsf{see} \ \mathsf{fig.} \ \mathsf{5}); \\ \mathsf{Pd}_{\mathsf{REV}} = \mathsf{inverse} \ \mathsf{power} \ \mathsf{loss} = \mathsf{V}_{\mathsf{R}1} \times \mathsf{I}_{\mathsf{R}} \ (1 - \mathsf{D}); \ \mathsf{I}_{\mathsf{R}} \ \mathsf{at} \ \mathsf{V}_{\mathsf{R}1} = \mathsf{rated} \ \mathsf{V}_{\mathsf{R}} \\ \end{array}$ 

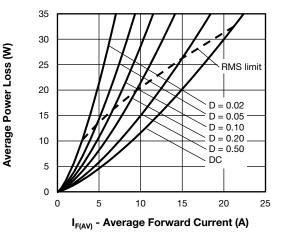


Fig. 6 - Forward Power Loss Characteristics, Per Diode

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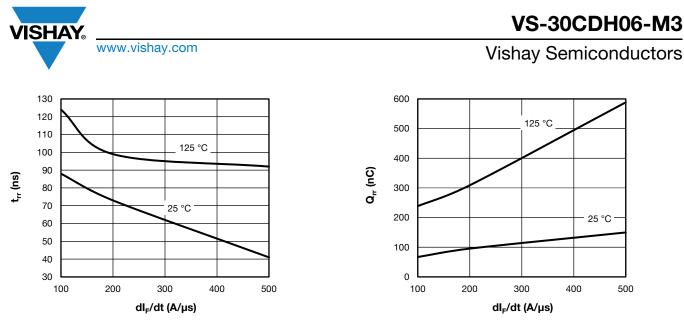


Fig. 7 - Typical Reverse Recovery Time vs. dl<sub>F</sub>/dt, Per Diode

Fig. 8 - Typical Stored Charge vs. dl<sub>F</sub>/dt, Per Diode

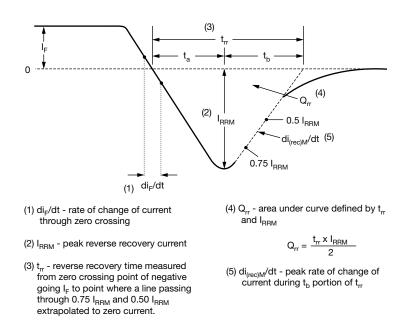


Fig. 9 - Reverse Recovery Waveform and Definitions

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## **ORDERING INFORMATION TABLE**

Device code	VC	20	•			00	
Device code	VS-	30	С	D	н	06	-M3
	1	2	3	4	5	6	7
	1	- Visl	nay Sem	nicondu	ctors pr	oduct	
	2	- Cur	rent rati	ng (30 A	A)		
	3	- Circ	cuit conf	figuratio	n:		
		C =	commo	on catho	de		
	4	- D=	SMPD	package	Э		
	5	- Pro	cess typ	be,			
		H =	hyperfa	ast recov	/ery		
	6	- Volt	age coo	de (06 =	600 V)		
	7	M3	B = halog	gen-free	e, RoHS	-compli	iant, and

ORDERING INFORMATION (Example)							
PREFERRED P/N	QUANTITY PER REEL MINIMUM ORDER QUANTITY PACKAGING DESCRIPTION						
VS-30CDH06-M3/I	2000	2000	13" diameter plastic tape and reel				

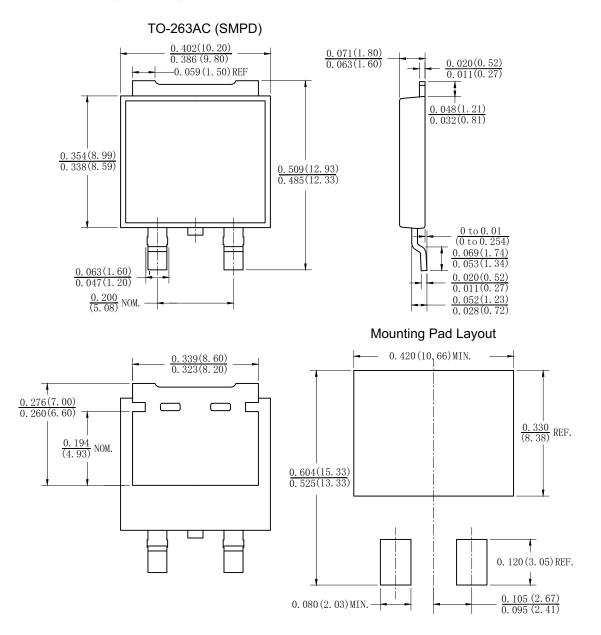
LINKS TO RELATED DOCUMENTS					
Dimensions www.vishay.com/doc?95604					
Part marking information	www.vishay.com/doc?95566				
Packaging information	www.vishay.com/doc?88869				
SPICE model	www.vishay.com/doc?96776				





TO-263AC (SMPD)

## **DIMENSIONS** in inches (millimeters)





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